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APPLICATION NO.	F	ILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/620,968	07/20/2000		Shunpei Yamazaki	0756-2183	4214	
22204	7590	05/18/2005		EXAM	EXAMINER	
NIXON PEABODY, LLP 401 9TH STREET, NW				HA, NAT	ha, nathan w	
SUITE 900		••	. ART UNIT	PAPER NUMBER		
WASHINGT	ON, DC	20004-2128	2814	<u> </u>		
				DATE MAILED: 05/18/200:	DATE MAILED: 05/18/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)					
Off A. C O	09/620,968	YAMAZAKI, SHUNPEI					
Office Action Summary	Examiner	Art Unit					
	Nathan W. Ha	2814					
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespondence address					
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply - If NO period for reply is specified above, the maximum statutory period w  - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	6(a). In no event, however, may a reply be timwithin the statutory minimum of thirty (30) days ill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONEI	nely filed s will be considered timely. the mailing date of this communication. O (35 U.S.C. § 133).					
Status							
1) Responsive to communication(s) filed on 07 M	arch 2005.						
2a) ☐ This action is <b>FINAL</b> . 2b) ☒ This	☐ This action is FINAL. 2b) ☐ This action is non-final.						
3) Since this application is in condition for allowar	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is						
closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.							
Disposition of Claims							
4) Claim(s) <u>2-25</u> is/are pending in the application.							
4a) Of the above claim(s) is/are withdrawn from consideration.							
5) Claim(s) is/are allowed.							
6)⊠ Claim(s) <u>2-25</u> is/are rejected.							
7) Claim(s) is/are objected to.							
8) Claim(s) are subject to restriction and/or	election requirement.						
Application Papers							
9) The specification is objected to by the Examine	r.						
10) The drawing(s) filed on is/are: a) acce	epted or b) objected to by the E	Examiner.					
Applicant may not request that any objection to the	drawing(s) be held in abeyance. See	e 37 CFR 1.85(a).					
Replacement drawing sheet(s) including the correcti	on is required if the drawing(s) is obj	ected to. See 37 CFR 1.121(d).					
11)☐ The oath or declaration is objected to by the Ex	aminer. Note the attached Office	Action or form PTO-152.					
Priority under 35 U.S.C. § 119							
12) Acknowledgment is made of a claim for foreign	priority under 35 U.S.C. § 119(a)	-(d) or (f).					
a) ☐ All b) ☐ Some * c) ☐ None of:	<b>,</b>						
1. Certified copies of the priority documents have been received.							
2. Certified copies of the priority documents have been received in Application No							
3. Copies of the certified copies of the priority documents have been received in this National Stage							
application from the International Bureau	application from the International Bureau (PCT Rule 17.2(a)).						
* See the attached detailed Office action for a list of the certified copies not received.							
		•					
Attachment(s)  1) X Notice of References Cited (PTO-892)  4) Interview Summary (PTO-413)							
1) M Notice of References Cited (PTO-892) 2) Motice of Draftsperson's Patent Drawing Review (PTO-948)	4) Interview Summary Paper No(s)/Mail Da						
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)	_	atent Application (PTO-152)					
Paper No(s)/Mail Date	6)						

#### **DETAILED ACTION**

## Claim Rejections - 35 USC § 112

- 1. The following is a quotation of the first paragraph of 35 U.S.C. 112:
  - The specification shall contain a written description of the invention, and of the manner and process of making and using it, in such full, clear, concise, and exact terms as to enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to make and use the same and shall set forth the best mode contemplated by the inventor of carrying out his invention.
- 2. Claim23-25 are rejected under 35 U.S.C. 112, first paragraph, as failing to comply with the written description requirement. The claim(s) contains subject matter which was not described in the specification in such a way as to reasonably convey to one skilled in the relevant art that the inventor(s), at the time the application was filed, had possession of the claimed invention. In this case, the newly added claims, claims 23-25, which contain s group of materials that was not described in the original specification as filed.

#### Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. Claims 2-3, 6, 9-10, 12-13,15-17, and 19-20 are rejected under 35 U.S.C. 103(a) as being unpatentable over Cunningham et al. (US 3,833,842, previously cited,

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hereinafter, Cunningham) and in view of Mori et al. (US 5,243,202, newly cited, hereinafter, Mori.)

In regard to claims 2, 9, 12, 16, and 19, in fig.12, Cunningham discloses a method of making a semiconductor device comprising steps of:

forming an insulating layer 119 comprising silicon nitride over a semiconductor substrate 70 by sputtering in an atmosphere consisting of nitrogen; see col. 12, lines 5-12. Cunningham does not expressly disclose that the amount of nitrogen is 75% volume or more.

Mori, in fig. 7, discloses an analogous semiconductor device including the silicon nitride comprising nitrogen at 75% or more in order to have a film that has high break down voltage (col. 30, lines 5-25.)

Therefore, it would have been obvious to one of ordinary skilled in the art at the time of the invention was made to use a high volume of Nitrogen as taught by Mori in order to improve the break down voltage of the film.

In regard to claims 3, 6, 10, 13, 17, and 20, the above-mentioned references teach the layer is made by using RF sputtering. See [0074], for example.

In regard to claims 9 and 12, Cunningham further discloses the use of Aluminum electrodes; see col. 2, lines 34-38.

5. Claims 4, 7, 11, 14, 18 and 21 are rejected under 35 U.S.C. 103(a) as being unpatentable over Cunningham and Mori's as applied to claims 2-3, 5-6, 8, 15-17, 19-20, and 22 above, and further in view of Nomoto et al. (US 5,225,364, hereinafter Nomoto.)

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In regard to claims 4, 7, 11, 14, 18 and 21 Cunningham discloses all of the claimed limitations as mentioned above except expressly teaches the device can be used in a matrix display. It is noted that the device of Cunningham in fact can be used in a matrix display device since it is a metallization device. It is used to carry out signal or power connection. However, in order to show the obviousness of this utility, Nomoto is incorporated herein. Nomoto discloses an analogous semiconductor device with substrate 1, silicon nitride insulating layer 5 and an aluminum electrode 8. The matrix has plurality devices that connect in rows and columns. Therefore, it is proper to combine this structure to a metallization structure in order to carry out the intended product, or design choice of a product.

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention was made to adapt matrix device as taught by Nomoto in Cunningham's in order to carry out the advantage mentioned above.

6. Claims 5, 8, 15, and 22 are rejected under 35 U.S.C. 103(a) as being unpatentable over Cunningham and Mori as applied to claims2-3, 6, 9-10, 12-13,15-17, and 19-20 above, and further in view of Yamazaki et al. (US 6,586,346, newly cited, herein, Yamazaki.)

In regard to claim 5, 8, 15, and 22, the above combination discloses all of the claimed limitations except the volumes of argon and halogen. Yamazaki discloses an analogous process and further includes the volumes of the argon and halogen as claimed in claims 5, 8, 15, and 22 in order to prevent fixed electric charges from being generated in the film (see the abstract.)

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Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention was made to use appropriate volumes of the argon and halogen materials in order to prevent fixed electric charges from being generated in the film.

### Response to Arguments

7. Applicant's arguments with respect to claims 2-22 have been considered but are moot in view of the new ground(s) of rejection.

#### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Nathan W. Ha whose telephone number is (571) 272-1707. The examiner can normally be reached on M-TH 8:00-7:00(EST).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael Fahmy can be reached on (571) 272-1705. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

Nathan Ha May 4, 2005

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